Client Ref. No. In1254WOUS

## DECLARATION FOR PATENT APPLICATION, POWER OF ATTORNEY & DESIGNATION OF CORRESPONDENCE ADDRESS

As below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

## SEMICONDUCTOR COMPONENT WITH CONDENSATORS BURIED IN THE SUBSTRATE AND INSULATED COMPONENT LAYER THEREOF

the specification of which (check one)
X is attached hereto.
was filed on as Application Serial No
and was amended on (if applicable).
I hereby state that I have reviewed and understand the contents of the above-identified specification including the claims, as amended by any amendment referred to above.
I acknowledge the duty to disclose information known to me to be material to the patentability of this application in accordance with 37 CFR §1.56(a).
PRIOR FOREIGN/PCT APPLICATION(S) FILED WITHIN 12 MONTHS (6 MONTHS FOR DESIGN) PRIOR TO THIS APPLICATION AND ANY PRIORITY CLAIMS UNDER 35 U.S.C. § 119(a)-(d)
I hereby claim foreign priority benefits under 35 USC § 119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

Prio	Priority Claimed			
Number	Country	Day/Month/Year Filed	Yes	No
DE 10242877.8	Germany	16, September 2002	x	
			<u>, e</u>	
	<del></del>			

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## CLAIM FOR BENEFIT OF PRIOR U.S. PROVISIONAL APPLICATION(S) (35 U.S.C. § 119(e))

I hereby claim the benefit under Title 35, United States Code, § 119 (e) of any United States provisional application(s) listed below:

Provisional Application Number	Filing Date
	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,

## CLAIM FOR BENEFIT OF EARLIER US/PCT APPLICATION(S) UNDER 35 U.S.C. § 120

I hereby claim the benefits under 35 USC § 120 of any United States application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of 35 USC § 112, I acknowledge the duty to disclose material information as defined in 37 CFR § 1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Appl. No.	Filing Date	Patented, Pending, Abandoned
PCT/DE03/03044	09/13/2003	Pending
		•

<u>Power of Attorney</u>: As a named inventor, I hereby appoint the Practitioners associated with the following Customer Number as its attorneys, with full power of substitution and revocation, to prosecute this application and any continuations, divisions, reissues, and reexaminations thereof, to receive the patent(s), to transact all business in the United States Patent and Trademark Office connected therewith and to act on INVENTOR'S behalf before the competent International Authorities in connection with any and all international applications filed.

Customer No. 48581- Infineon Technologies

Please recognize or change the correspondence address for this application to the address associated with the above-mentioned Customer Number. Please direct all telephonic and facsimile communications to:

Anthony P. Curtis, Ph.D. Tel.: (312) 321-4299

I hereby declare that all statements made herein on my own knowledge are true and that all statements made on information and belief are believed to be true, and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both under 18 USC §1001 and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

1-00	Full Name of First Inventor: Franz HOFMANN					
•	Inventor's Signature: Fru M	Date:	F.L.	3.	2025	-
	Residence: Herbergstr. 25B, D-80995 München, Germany					DEX
	Citizenship: German					
	Mailing Address: Herbergstr. 25B, D-80995 München, Germany	/				
						1
2-10	Full Name of Second Inventor: Volker LEHMANN	1				
	Inventor's Signature:	Date:			·	ファイ
•	Residence: Geyerspergerstr. 53, D-80689 München, Germany					DEX
	Citiz <del>enshi</del> p: German -					
	Mailing Address: Geyerspergerstr. 53, D-80689 München, Germ	nany				
2-00	C (Many of Third In contain I will be DICAL)					
3-00	Full Name of Third Inventor: Lothar RISOH		Feb -	· ·	10.5	
	Inventor's Signature:	Date:	rey.	7. 20	/03	DEX
	Residence: Tizianstr. 27, D-85579, Neubiberg, Germany					シン
	Citizenship: German		-	··		
	Mailing Address: Tizianstr. 27, D-85579, Neubiberg, Germany	***************************************				
4-00	Full Name of Fourth Inventor: Wolfgang RÖSNER			<u>.</u>		
1	Inventor's Signature: Wolfgang Rossus	Date: 7	Fol 3	70	05	
	Residence: Sudetenstr. 23, D-85521 Ottobrunn, Germany	1 Date.	<i>CO.</i> C	1		DEX
	Citizenship: German					307
	Mailing Address: Sudetenstr. 23, D-85521 Ottobrunn, Germany					
	Maning Address. Sudetensit. 25, D-63321 Ottobium, Germany		*****************	· · · · · · · · · · · · · · · · · · ·	•	
5-w	Full Name of Fifth Inventor: Mighael SPECHT					
	Inventor's Signature: (Millard 52)	Date:	teb	3, 2	2005	
·	Residence: Schraudolphstr. 42. D-80799, München, Germany					DEX
	Citizenship: German					
	Mailing Address: Schraudolphstr. 42, D-80799, München, Germ	nany				
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DE 10242877.8	Germany	16, September 2002	x	
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Provisional Application Number	Filing Date
1	

## CLAIM FOR BENEFIT OF EARLIER US/PCT APPLICATION(S) UNDER 35 U.S.C. § 120

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Anthony P. Curtis, Ph.D. Tel.: (312) 321-4200; Fax: (312) 321-4299

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Full Name of First Inventor: Franz HOFMANN						
Inventor's Signature:	Date:					
Residence: Herbergstr. 25B, D-80995 München, Germany						
Citizenship: German						
Mailing Address: Herbergstr. 25B, D-80995 München, Germany	E Absorber Delensamentaria i a un auf museum and a P anno sans a series					
Full Name of Second Inventor: Volker LEHMANN	Date: 3.2.05					
Inventor's Signature: Lollar Jeh m	Date: J. W. UG					
Residence: Geyerspergerstr. 53, D-80689 München, Germany						
Citizenship: German						
Mailing Address: Geyerspergerstr. 53, D-80689 München, Germ	any					
Full Name of Third Inventor: Lothar RISCH						
Inventor's Signature:	Date:					
Residence: Tizianstr. 27, D-85579, Neubiberg, Germany						
Citizenship: German						
Mailing Address: Tizianstr. 27, D-85579, Neubiberg, Germany						
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Full Name of Fourth Inventor: Wolfgang RÖSNER						
Inventor's Signature:	Date:					
Residence: Sudetenstr. 23, D-85521 Ottobrunn, Germany						
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Mailing Address: Sudetenstr. 23, D-85521 Ottobrunn, Germany						
Γ						
Full Name of Fifth Inventor: Michael SPECHT						
Inventor's Signature: Date:						
Residence: Schraudolphstr. 42, D-80799, München, Germany						
Citizenship: German						
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